

A Solder Based Self Assembly Project In An Introductory IC Fabrication Course

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ABSTRACT

Integrated circuit (IC) fabrication principles is an elective course in a senior undergraduate and early graduate student's curriculum. Over the years, the semiconductor industry relies heavily on students with developed expertise in the area of fabrication techniques, learned in an IC fabrication theory and laboratory course. The theory course gives importance to the physics of manufacturing techniques and is often attached to a subsequent semester laboratory curriculum. The pre-requisite requirement of the theory component for a laboratory course requires students to enroll for two courses in separate semesters and is not an option for all students. Hence, an innovative student project is intended in the theory curriculum to give hands-on experience on the processes. The IC fabrication course is usually associated with high enrollment of students, leading to fewer laboratory experiments. The physics of IC fabrication techniques is important, but few students may perceive the theory as important with no laboratory experience. To improve the course and give students hands-on practice with existing state-of-the-art processing facilities, a tailored project was added to the syllabus. A solder-based self assembly (SBSA) project was introduced in the curriculum for the first time at the University of Alabama in Fall 2011. The student projects were designed in a way to provide an alternative to conventional time-intensive, high cost, and highly tool dependent IC fabrication lab experiments. SBSA forms three dimensional (3D) structures when applied to two dimensional (2D) patterns. The schedule was designed to accommodate theory classes aligned with the fabrication steps and completed by students. The project involved a brainstorming session, a design stage to develop 2D patterns using AutoCAD software, a deposition process, a lithography step, a dip soldering step, a reflow process, scanning electron microscope (SEM) imaging, and a final project presentation. Other processes required to complete the project were performed by the instructor. In general, students showed interest in working in teams, completing the project, and recommended to continuing the SBSA project in future IC fabrication course work. The SBSA project is cost effective and less tool dependent for incorporation in a semester long course. In addition, the project is time effective from both student and instructor perspectives.

Keywords: Self Assembly; Integrated Circuit; Silicon Processing; Semiconductors

INTRODUCTION

Integrated circuit (IC) fabrication courses rely heavily on fundamental physics behind each of the processing tools used in the semiconductor industry (Khaliq, 2001; Hong, & Ha, 2013). The course serves as an elective subject in an undergraduate microelectronics stream and also as a foundational part of the curriculum in a microelectronics/VLSI master level program. VLSI technology proves to be a multidisciplinary field, hence the enrollment is not only limited to electrical engineering students, but available to students from different departments including materials science, chemical engineering, metallurgical engineering, physics, and chemistry. The enrollment in a IC fabrication course is always expected to be high, due to the high number of job offerings in CMOS technology industry. Students gain extensive knowledge in the area of technology in a semester course and find suitable jobs in semiconductor and nanotechnology fields (Voros, 2014; Pan, Yang, Kai, Zhang, & Yang, 2008). There are two important reasons for teaching integrated circuits from both theoretical

and fabrication technique viewpoints. The course prepares students for further independent study in either academia or industry. In an industry job, the newly recruited process engineer is expected to know the principles of fabrication techniques. The laboratory experience obtained in school provides students with a relevant and marketable skill. For an advanced student in academia, the laboratory-based processing work serves as an introduction to the experimental research work.

Traditionally, IC fabrication curriculum is divided into two courses: theory and laboratory, each taught in separate semesters (Neudeck, Anderson, & Silva, 1971; Naseem, Brown, 1999; Parke, Burkett, Duttagupta, Honfhine, Erickson, Holscher, Boorum, Rosato, & Clifford, 1999). The theory is a prerequisite for the laboratory course. Two separate semesters are required, due to high enrollment and the amount of time required for intensive laboratory training and experiments (Parent, Basham, Dessouky, Gleixner, Young, & Allen, 2005). The two courses per year, while providing vast knowledge, are not always an option for all students. Hence, we observe a trend of a high number of students enrolled in a theory class for a semester and few students enrolled for the laboratory class. To combine the two and complete in one semester, an innovative student laboratory project was integrated in the IC fabrication course at the University of Alabama in Fall 2011.

The course involved a unique project, where a group of students completed five tasks: photomask design, a deposition or a lithography step, a dip soldering process, solder reflow, and scanning electron microscope (SEM) imaging of 3D structures. The project provided a complete end-to-end processing exercise. The steps involved in this activity closely resemble the primary steps an engineer walks through, in the IC fabrication industry, which includes: oxidation, metal deposition, patterning, diffusion, dry etching, wet etching, and SEM imaging to check the patterns. Diffusion, oxidation, and dry etching steps were not included in the laboratory project as they were not required in completing the SBSA project. The laboratory assignment was given sufficient time over an entire semester and tasks were successfully completed by students. A final student survey about the laboratory project was administered and suggestions were provided by students for improving the laboratory part in the future introduction to IC fabrication curriculum. The SBSA project proves to be economically viable and time appropriate for inclusion in a theory curriculum to be offered in a semester long course.

BACKGROUND

IC fabrication curriculum provides the necessary skill set for semiconductor and VLSI technology industry jobs, and is well known (Allen, Strader, & Geiger, 1982). The lack of laboratory experience may deter students in job prospects (Hunt, 2006). However, to include laboratory projects in a theory class is not feasible due to high enrollment of students. Hence, an innovative project needs to be designed which fits in the curriculum and thereby provides necessary silicon processing skills for students on campus. Designing a student project in an IC fabrication curriculum needs to fulfill two objectives: a feasible project to complete within a semester and a project that should provide CMOS processing experience in the areas of deposition, photolithography, etching, and imaging steps. Some popular practices followed in a semester long IC fabrication laboratory, a three credit hour undergraduate/graduate lab course, at the University of Arkansas and Boise State University are mentioned below (Naseem, Brown, 1999; Parke, Burkett, Duttagupta, Honfhine, Erickson, Holscher, Boorum, Rosato, & Clifford, 1999).

- A six level mask set is used in the lab course. The IC chip contains 40 test structures which includes resistors, capacitors, diodes, transistors, and alignment marks.
- The laboratory course is divided into seven experiments. The wafers are thoroughly cleaned via sulfuric acid/hydrogen peroxide, or piranha etching.
- The silicon wafers are oxidized via dry oxidation method.
- Photolithography step is followed using one of the six masks. Negative photoresist is spin-coated on these wafers and further exposed and developed.
- Boron diffusion is followed after lithography. The sheet resistance after boron diffusion is measured using a Keithley four point probe system.
- Selective phosphorous diffusion is performed using lithography, pre-deposition, and drive-in diffusion methods. Sheet resistance and junction depth are measured using a four point probe instrument.

- Selective gate oxide is grown via lithography and dry oxidation. Oxide thickness is measured using ellipsometry.
- Photolithography is completed to obtain contact holes and vias for metallization. The metallized contacts and holes are used to drive voltage/electric field to the fabricated device.
- Capturing and viewing device patterns in an electron microscope.

The process flow mentioned above provides a detailed overview and necessary skills in the area of CMOS technology, however the described method is not particularly cost effective. In addition, the whole process depends on various tools such as oxidation, diffusion, photolithography, metal deposition, four point probe measurement, and electron microscopy imaging. The major component of cost includes production of a six photomask set. Although the practice followed is close to an industry requirement of processing devices, the cost factor and high number of tools are difficult to maintain in a low budget environment. The self assembly project uses the photolithography technique, a three photomask set, an electron microscope, deposition of metals, and eliminates oxidation and diffusion process, making it budget friendly.

The fabrication steps involved in the SBSA project include deposition, patterning, and wet etching which can be completed in a cleanroom laboratory. SBSA is an emerging technology to build three dimensional (3D) structures from two dimensional layouts. It has been used by scientists to achieve micro-scale 3D structures (Gracias, Kavthekar, Love, Paul, & Whitesides, 2002; Harsh & Lee, 1998; Yang, Liu, Wang, & Tian, 2011; Yang, Wang, Liu, & Tian, 2012). SBSA is a simple and inexpensive method to create 3D structures (Rao, Lusth, & Burkett, 2009; Kong, Jeon, Au, Hwang, & Lee, 2011). Highly parallel fabrication of 3D structures is made possible by the SBSA approach (Rao, Lusth, & Burkett, 2012). The microscale 3D structures find various research applications (Gracias, Tien, Breen, Hsu, & Whitesides, 2000; He, Guan, & Lee, 2006; Howe, 1988; Mirkin, Letsinger, Mucic, & Storhoff, 1996; Randall, Leong, Bassik, & Gracias, 2007; Park, Kim, Sung, & Pak, 2003; Rao, Lusth, & Burkett, 2011; Oraon, Kumar, Srivastava, & Rao, 2013) that may encourage students to continue research in the 3D microelectronics field in the future. Since the SBSA process was thought to provide significant research experience and a feasible process to complete within a semester, the project was added to the existing IC fabrication theory class. The laboratory project was designed in a view to provide processing experience to a maximum number of students in a given time. The students were divided into groups of four and no more than five to have a fair distribution of workload in the SBSA project. Others concluded that working in groups show a high learning curve (Fuller & Hirschman, 1997; Yan-Ming, 2010). A minimum of five tasks were allotted to each group in addition to the final project presentation at the end of the semester. Complete SBSA processing by individual groups would have made the laboratory work flow extremely tedious and time consuming for students and time intensive for the instructor. Besides, the IC fabrication theory component already requires students to dedicate a significant amount of time.

The project was initiated by a brainstorming session for all groups, with a plan to design novel 2D patterns on paper. Brainstorming is considered to be one type of problem-solving technique (Oslapas, 1993) and the practice is observed to help students in solving research problems or industry problems in the future. The project was completed by considering student opinions in the form of a survey. Surveys are considered time effective means of collecting results (Lazic, Pavlina, & Pongrac, 2010; Shanableh, Omar, Younes, & Barakat, 2003). Surveys, in the form of student opinions, were obtained to check the number of objectives met in the course and to improve the laboratory activity for the future.

The SBSA project involved designing a mask set which is used in lithography processing steps. AutoCAD is a general platform to develop the photomask design, which forms an essential component of silicon processing. New devices are realized in the CAD design tool before sending to foundries. The mask design, via AutoCAD, is normally eliminated in a traditional IC fabrication curriculum due to the high learning curve (Parent et al., 2005). This hampers student progress in converting ideas into processing reality. One of the objectives in introducing the SBSA project in an IC fabrication curriculum was to demonstrate the importance of CAD design in the overall silicon processing sequence and get students started on CAD design. In SBSA, three photomasks were required to obtain the 3D structures (Rao, Lusth, & Burkett, 2013). The three photomasks were labeled: SAC, METAL, and SOLDER. The SAC mask is required to etch a window surrounding the sacrificial layer. The window region keeps the base of the 3D structure fixed to the silicon substrate. The METAL mask is required to perform pattern plating

and forming the side faces of the 3D structure. The SOLDER mask is required to isolate the area of soldering from the substrate. The complete mask design involves placing alignment features on each mask to connect the three photomasks and drawing the three photomask entities on the same AutoCAD file using three different layers, which required more time to complete. Hence students were asked to develop a set of designs which was multiplied across a 4-inch diameter wafer in the METAL mask layer. The other two layers and alignment features were introduced by the instructor. Thus students were able to envision the 3D structure based on 2D designs in AutoCAD.

Another objective included in the SBSA project was to assemble a conventional process traveler that followed the processing work flow. Reading a process traveler is always included in an IC fabrication laboratory course. However, this concept is typically eliminated in an IC fabrication theory curriculum. Hence, a short description and demonstration were included in the project overview lecture. The process traveler, described to students in completing the SBSA project, is shown in Table 1. The process traveler for SBSA was derived in our previous work (Rao et al., 2012).

This paper discusses the results of teaching IC fabrication principles with an integrated laboratory project at a university using two primary processes: evaporation and photolithography. Students generated novel designs which were easily integrated in research work. Students also provided input to the application of SBSA 3D structures. The project approach, with a final survey based on student opinions, is discussed in this paper. Both graduate and undergraduate students participated in this course.

Table 1. Process Traveler Used In SBSA Student Project

Process	Tool used	Time	Expected parameters (thickness)
Deposit SiO ₂ as sacrificial layer	E beam evaporator	-	200 nm
Resist deposit	Spin coater: 2500 rpm	30 seconds	2.5 μm
Photolithography	Suss aligner (SAC MASK)	6 seconds	-
SiO ₂ etch	Buffer Improved HF solution	15 seconds	-
Resist strip	Ultrasonic bath using acetone solution	10 minutes	-
Deposit Ti and Cu	Electron beam evaporator	-	17 nm of Ti and 75 nm of Cu.
Resist deposit	Spin coater tool with speed of 2500 rpm	30 seconds	2.5 μm
Photolithography	Suss aligner (METAL mask)	6 seconds	-
Copper plating	DC electroplating	40 minutes	4.9 μm
Resist strip	Ultrasonic bath using acetone solution	10 minutes	-
Cu etch	APS copper etchant solution	60 seconds	-
Ti etch	TFT Transene etchant	60 seconds	-
Resist deposit	Spin Coater tool with speed of 2500 rpm	30 seconds	2.5 μm
Photolithography	Suss aligner (SOLDER mask)	6 seconds	-
Dicing	Dicing pen	-	-
Dip soldering	Hot plate with molten solder maintained at 97 °C	90 seconds	-
Resist strip	Ultrasonic bath using acetone solution	10 minutes	-
Sacrificial etching	Buffer Improved HF solution	6 hours	-
Reflow	Aqueous HCL solution maintained at 60 °C	30 seconds	-
SEM imaging	-	-	-

EXPERIMENTAL PROCEDURES

The laboratory experiments were initiated by forming four groups of students. The students in a group had equal numbers of undergraduate and graduate students. The group members were selected in a sense that graduate students took the leadership roles and undergraduate students obtained the necessary research experience. The groups were given the tasks as shown in Table 2. Table 2 shows that four tasks: mask design, dip soldering, reflow, and SEM imaging were allotted to all groups. Patterning, deposition, and SEM imaging required pre-requisite training and certification to use the tool. Hence, the groups were formed to have at least one student with prior experience and certification in deposition or patterning and SEM usage. Generally, graduate students working in the area of materials possesses required expertise and certification in the mentioned tools. The processing details, shown in Table 3, indicate that the individual groups were given tasks to move the project forward. The approach ensured that individual group's task was bound by time. Each of the processing steps were given a maximum of seven days to complete.

The SBSA project consists of 14 processes to build 3D structures on a silicon wafer. SBSA includes a few wet processes including wet etching of SiO₂, titanium (Ti), and copper (Cu), resist stripping, and Cu direct current (DC) electroplating. The wet etching and electroplating processes were handled by the instructor, to avoid unintentional chemical hazards. The dip soldering and reflow processes were completed by students and monitored by the instructor.

Table 2. Tasks Allotted To Student Groups

Groups	Tasks
1	Mask design, photolithography, dip solder, reflow, and SEM image
2	Mask design, evaporation, dip solder, reflow, and SEM image
3	Mask design, photolithography, dip solder, reflow, and SEM image
4	Mask design, evaporation, dip solder, reflow, and SEM image

Table 3. Processing Steps Followed By Different Groups

Process	Operator
Oxide deposition	Group1
Photolithography	Group2
Wet etching	Instructor
Ti and Cu evaporation	Group3
Photolithography	Group4
Copper plating	Instructor
Resist stripping	Instructor
Metal etching	Instructor
Photolithography	Instructor
Dip soldering	All groups separately supervised by Instructor
Dicing	Instructor
Sacrificial etching	Instructor
Reflow	All groups separately supervised by Instructor
SEM imaging	All groups

Brainstorming Session To Produce Mask Design

A brainstorming session on the SBSA project was included as a part of the laboratory project. A 30 minute lecture was given on the overview of the SBSA project and followed by a brainstorming session for 20 minutes. Students were shown the process traveler, mentioned in Table 1, and a few research results were provided to initiate the brainstorming between students within their group. Brainstorming was included to find innovative 2D pattern designs developed by students. The 3D folding success of regular square faces and truncated square faces were shown to students and are depicted in Figure 1 (Rao et al., 2012). The student groups were evaluated based on at least five innovative face designs for a fixed nominal (linear) length of 300 μm and a fixed base length of 300 μm . The nominal length and base length are best described in Figure 2. The six best face designs were chosen by the instructor and were shared with students. Students were asked to design the six selected face designs on four different variants (three sided base to six sided base). The final design was completed in AutoCAD software.

Additional out-of-class help was provided to answer any student questions. The final student designs were verified and assembled in a single layer and labeled as the METAL mask by the instructor. Two additional mask designs: SAC mask to perform sacrificial etching and SOLDER mask to do selective soldering on the metal patterns, were designed by the instructor and were sent for mask production.

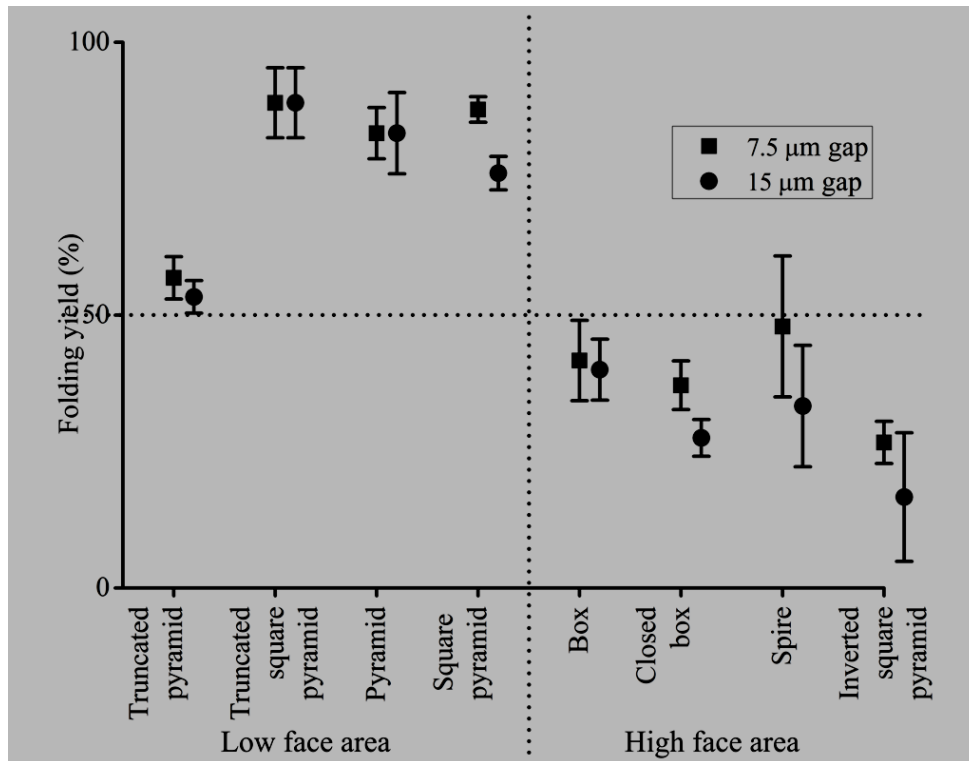


Figure 1. Folding Yields For Face-Soldered Polyhedra At Two Different Gap Spacings. The Face Thickness Is Fixed At 4.9 μm.

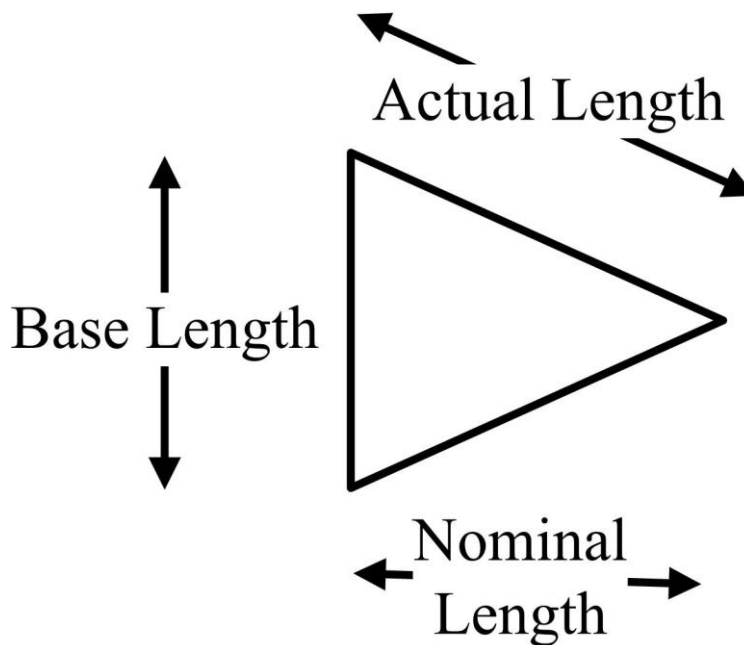


Figure 2. Picture Used To Demonstrate The Difference Between Nominal, Actual And Base Length.

Student Experiments

Student team completed the necessary tasks as per the time slot provided to them. A few experimental photographs, captured by students, are illustrated in Figure 3. The student’s work was demonstrated in the final presentation spanning 20 minutes. The final presentation indicated that, in general, students were able to complete the project in a semester and demonstrated necessary processing knowledge. In addition, a few groups conducted thickness measurements using a profilometer. The authors developed a real time video capturing capability in the laboratory to help students observe the self assembly process. A sample of the reflow process can be viewed in the uploaded video file (Rao, 2012).

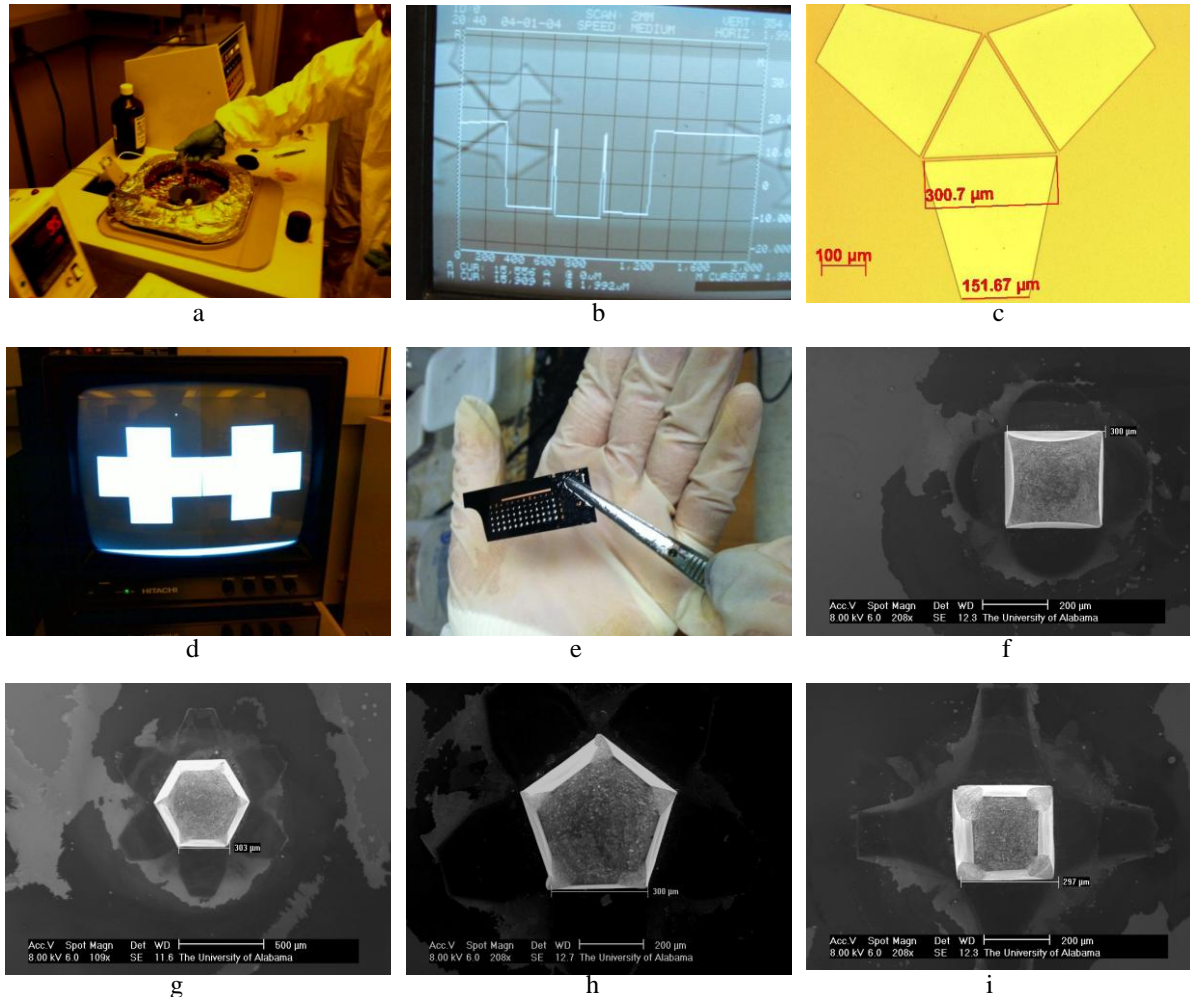


Figure 3. Experimental images captured by students showing; (a) spin coating, (b) profilometer scanning to determine thickness of metal deposited, (c) developed metal patterns, (d) alignment marks for performing second lithography, (e) dip soldered sample, and (f, g, h, i) SEM images of various folded 3D structures.

Research Costs

The total cost of the student project is shown in Table 4. Among all of the steps, mask generation was the most expensive. However one must note that these masks were reused for research purposes and hence were not considered in the student project cost component. The other costs mentioned in the table are tool usage costs at the University of Alabama microfabrication facilities. The miscellaneous costs includes two silicon wafers, metal etchant, oxide etchant solutions, resists, and other solvents such as acetone, isopropanol and deionized water. These

solutions and wafers were a part of the materials purchased for research and thus the cost was not factored into the student laboratory project. Overall the student project cost was \$640 USD which includes evaporation, patterning and SEM usage.

Table 4. Cost Of The Project

Steps	Costs (USD)
Masks	1500
Evaporation	120
Patterning	120
SEM imaging	400
Miscellaneous	200

Assessment

A survey containing various questions and suggestions to improve the laboratory component in the course was given to students in the class. Student feedback is considered the best and time effective assessment tool in undergraduate and graduate teaching (Lazic et al., 2010). Students answered the feedback questions in the form of ratings ranging from 1 to 5, where 1 and 2 indicated negative responses and 4 and 5 indicated positive responses. The option of 3, indicating a neutral response, was also provided in the survey. Ratings of 4 and 5 were grouped together and 1 and 2 ratings were grouped together for positive and negative response markers, respectively. The survey results were analyzed to improve the laboratory part for future semesters.

EXPERIMENTAL RESULTS

Brainstorming Session To Produce Mask Design

The brainstorming session led to different student designs drawn on paper as shown in Figure 4. This shows that a lecture of 30 minutes prompted groups of students to develop at least six designs. A few designs were common between the groups. Six popular designs were selected by the instructor and students provided the primitive designs in AutoCAD software. The six common designs were labeled: *rounded-corner*, *hour-glass*, *trumpet*, *trash can*, *semi circle*, and *funnel*. The final mask design provided by students is shown in Figure 5. The figure shows that the selected designs were repeated for four variants. The student's mask designs were later arranged in a new CAD file. Two other layer designs: SAC and SOLDER were wrapped along the students mask design and sent for mask generation. Three glass masks with six novel designs were produced from the student brainstorming session.

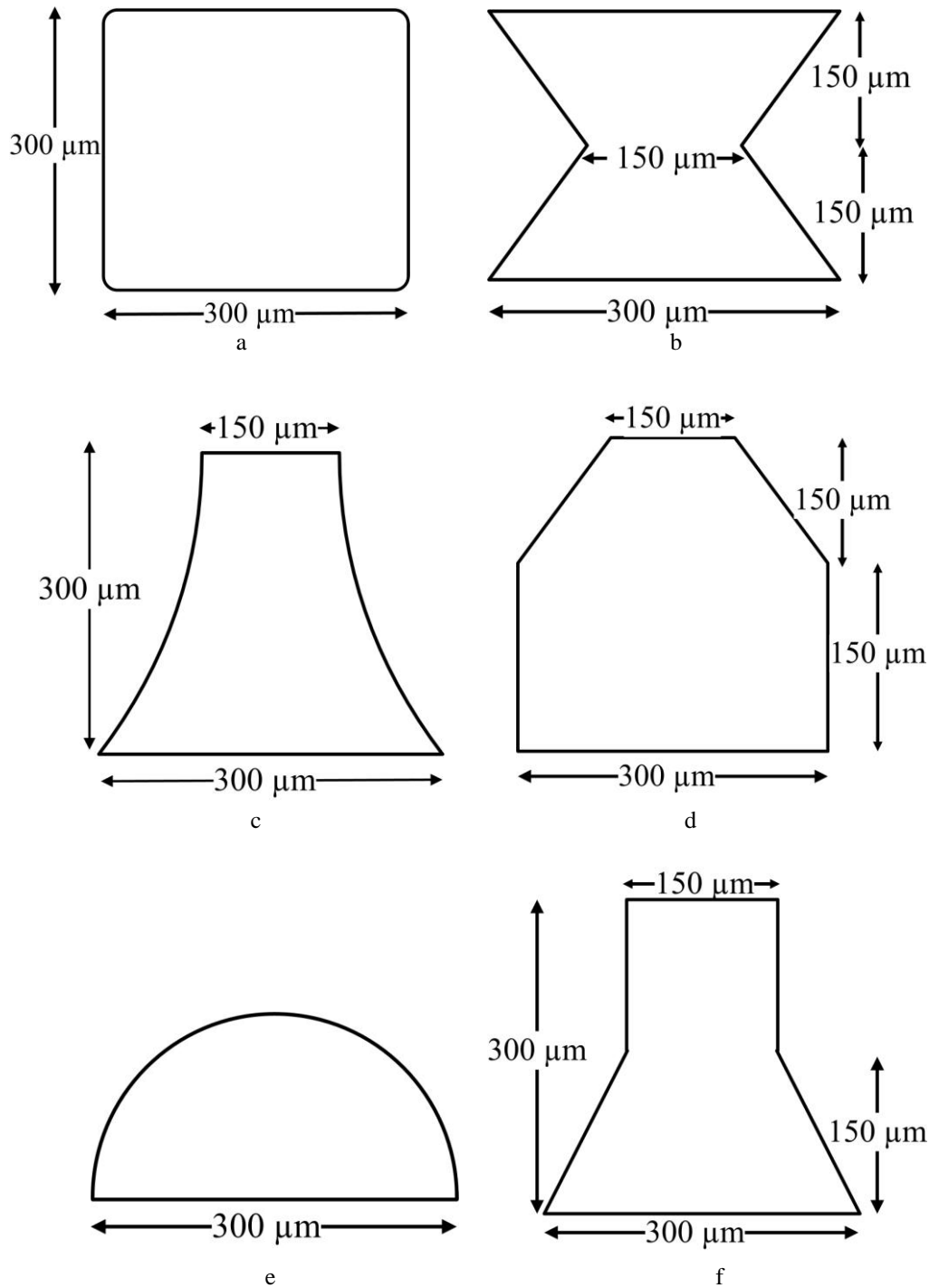


Figure 4. Picture showing design by group of students during brainstorming session in class. Note that the diagrams are not to scale. Six designs: (a) rounded-corner, (b) hour-glass, (c) trumpet, (d) trash-can, (e) semi-circle, and (f) funnel are shown.

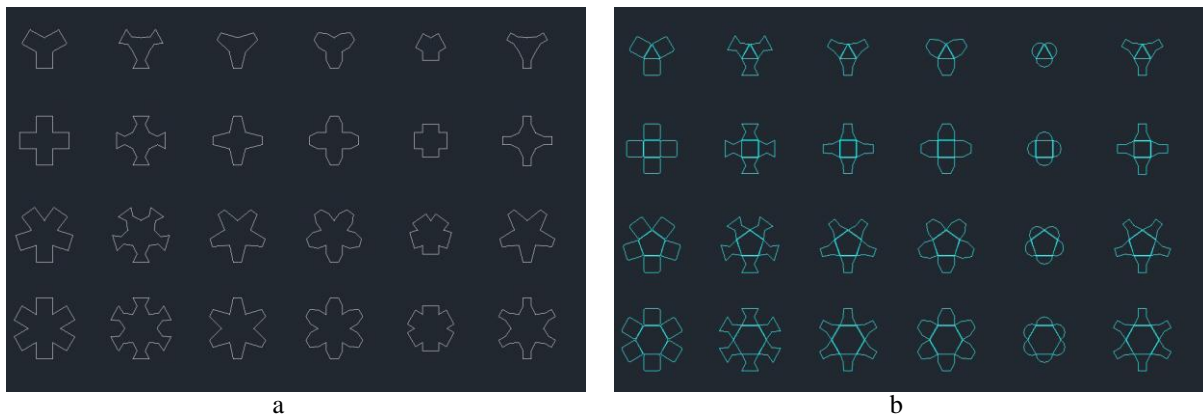


Figure 5. Picture showing (a) mask design developed by the instructor and (b) mask design developed by student groups. Six designs starting from left to right: *rounded-corner*, *hour-glass*, *trumpet*, *trash-can*, *semi-circle*, and *funnel* are shown.

Impact On Research

The brainstorming session resulted in innovative designs. Six designs: *rounded-corner*, *hour-glass*, *trumpet*, *trash-can*, *semi-circle*, and *funnel*, when folded into 3D structures, provided space uncovered by metal. This could lead to solder leakage problems when exposed to temperatures above the melting point of the solder alloy. The new designs can be filled with high temperature solder alloy to avoid leakage at lower temperatures and is an area to be explored in future SBSA research. One student group suggested using SBSA 3D structures as interconnects with an addition of insulator surrounding the 3D structures as shown in Figure 6. The addition of insulator reduces the parasitic capacitances and thereby improves delay times. The authors appreciate the approach and would like to integrate this input into their future research scope of interest.

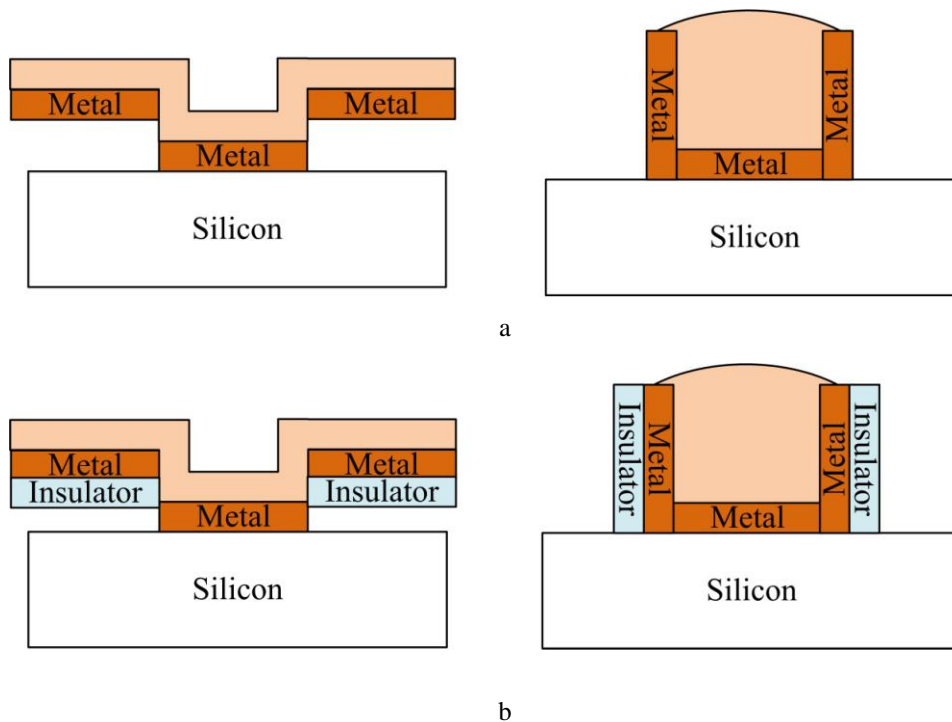


Figure 6. Schematic image showing (a) current material stack to form 3D structure and (b) new material stack to form 3D structure to avoid parasitic capacitance as suggested by a student group.

Finally, folding and bridging yields of the student’s designs were determined. Bridging refers to hinging of all metal faces with the central metal face. Bridging yield was evaluated by visual inspection in a SEM for the number of entities which showed complete hinging. Folding yield was evaluated for only successfully bridged patterns. The unbridged patterns were ignored for folding evaluation. Folding yield was estimated by visual inspection in a SEM for the number of successfully folded 3D structures. Figure 7 shows bridging and folding yields of the student designs. The *rounded-corner* design showed higher bridging yield than the rest and the *funnel* design showed lower bridging results. In the folding results, the *trumpet* design showed consistent results compared to the rest. Further research on the geometry of the *funnel* design and *trumpet* design will be conducted in the future.

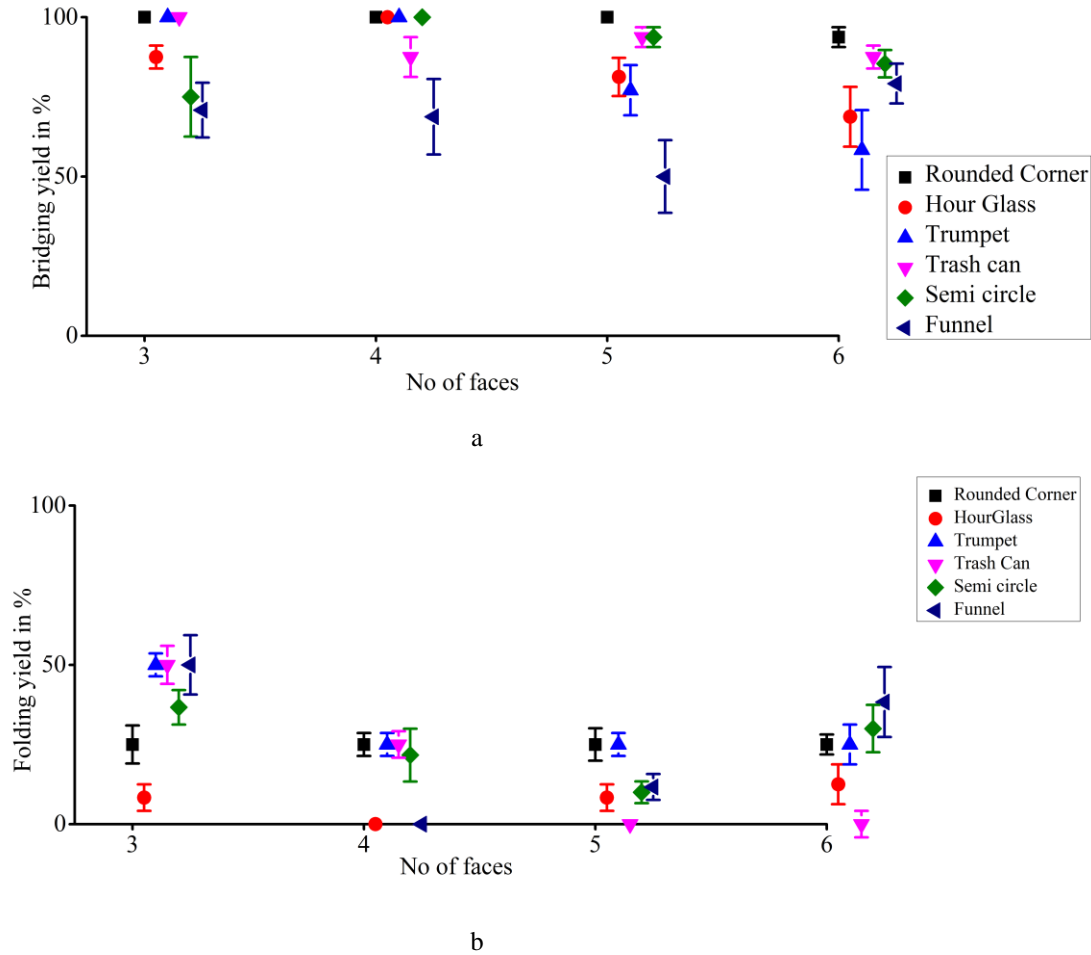


Figure 7. (a) Bridging and (b) folding yields of patterns designed by students in the course.

Assessment Results

The survey results shown in Figure 8 (a) suggests that although prior experience of silicon processing among students were low, the SBSA project in the laboratory helped students understand IC fabrication principles well. The majority of students enjoyed working in a team, which is crucial for their professional development in the future. The students followed the process traveler and demonstrated an understanding of the traveler. Most engineers in the semiconductor industries are required to follow an established traveler. Figure 8 (b) suggests that a majority of students were positive about the overview lecture provided describing the project. A majority of students were satisfied with the laboratory hands-on experience in regards to completing this project. Students recommended a similar project for future IC fabrication courses. Students were pleased with the time dedicated for the project.

However, student opinions on research related to self assembly were not completely positive. Hence the integration of SBSA project in a IC fabrication course failed to influence students, to pursue more self assembly research. The authors believe that students do not appreciate the natural self assembly process as a technological innovation and hence student interest in the area of self assembly research was low. Due to time limitations, the instructor was unable to discuss the applications of self-assembled 3D structures in the microelectronics field and may have added to the low interest rating for students.

Figure 9 shows that students enjoyed SEM imaging and reflow processing steps compared to other processing steps in the SBSA project. The reflow process included a video recording of the folding process for micro-scale 3D structures. The video capturing facility was set up by the instructor using a super-macro lens and an optical camera. The real-time folding of micro-scale 2D metal faces was viewed clearly via the video setup and hence student's positive rating was justified. SEM imaging was the final step in the project, where students observed successfully folded or failed 3D structures, hence a positive rating for the SEM imaging step was expected. Students gave a low rating to mask design. The mask design using AutoCAD software has a high learning curve. An expert mask designer normally uses an available template and modifies the existing template to develop new designs. Most of the students were novice users of AutoCAD software and this may have possibly led to low ratings. Evaporation, due to the time intensive nature, was rated low compared to other steps involved in the laboratory project. This was especially true for students performing Ti and Cu evaporation spending 4 hours on a single step compared to the reflow step of 30 minutes, SEM imaging of 30 minutes, and lithography of around 1 hour. Hence, the low interest in evaporation was understood. The low interest in dip soldering process was unexpected since the time taken to complete the dip soldering process was less than 10 minutes. The authors believe that students found the process to be trivial and that it did not offer any new learning component. The dip soldering process involved cleaning samples in acidic flux which needed certain safety precautions to be undertaken by the student to perform this step. The authors believed that these precautions acted as overhead for a trivial process and reduced the student ratings.

Time Spent By Instructor

The time spent on the overall processing steps starting with formation of student groups to the student presentation is shown in Table 5. A total of 20.25 hours was devoted by the instructor in supervising and providing patterns to complete the laboratory project besides teaching the IC fabrication theory course. However with close to 20 hours of supervision and an average time of less than 5 hours spent by individual students, the laboratory project was seen as a time appropriate process to be included in any future IC fabrication curriculum.

CONCLUSIONS

The brainstorming session demonstrated six novel designs produced by students. Students, in groups, demonstrated required CAD skills to design the photomask. Given more time, students could have designed a complete set of photomasks. Students showed interest by providing a few improved design suggestions to avoid fringing capacitance for 3D structures to be used as 3D interconnects. This demonstrated that students showed interest and provided valuable feedback to the self-assembly research topic. Student assessment results indicated that the SBSA project was an interesting topic to be included in a IC fabrication theory curriculum. Various aspects of student learning outcomes, in the form of ABET's (a-k), were successfully achieved. The SBSA project was found to be time appropriate and cost effective to be included in a future IC fabrication theory course. The authors realized that a few tasks, such as evaporation of Ti and Cu, will be included as an instructor activity since evaporation is the most time consuming step in this project and students tend to lose interest in this step. Overall, the SBSA project was a perfect fit to include laboratory hands-on experience with the IC fabrication theory class in a semester.

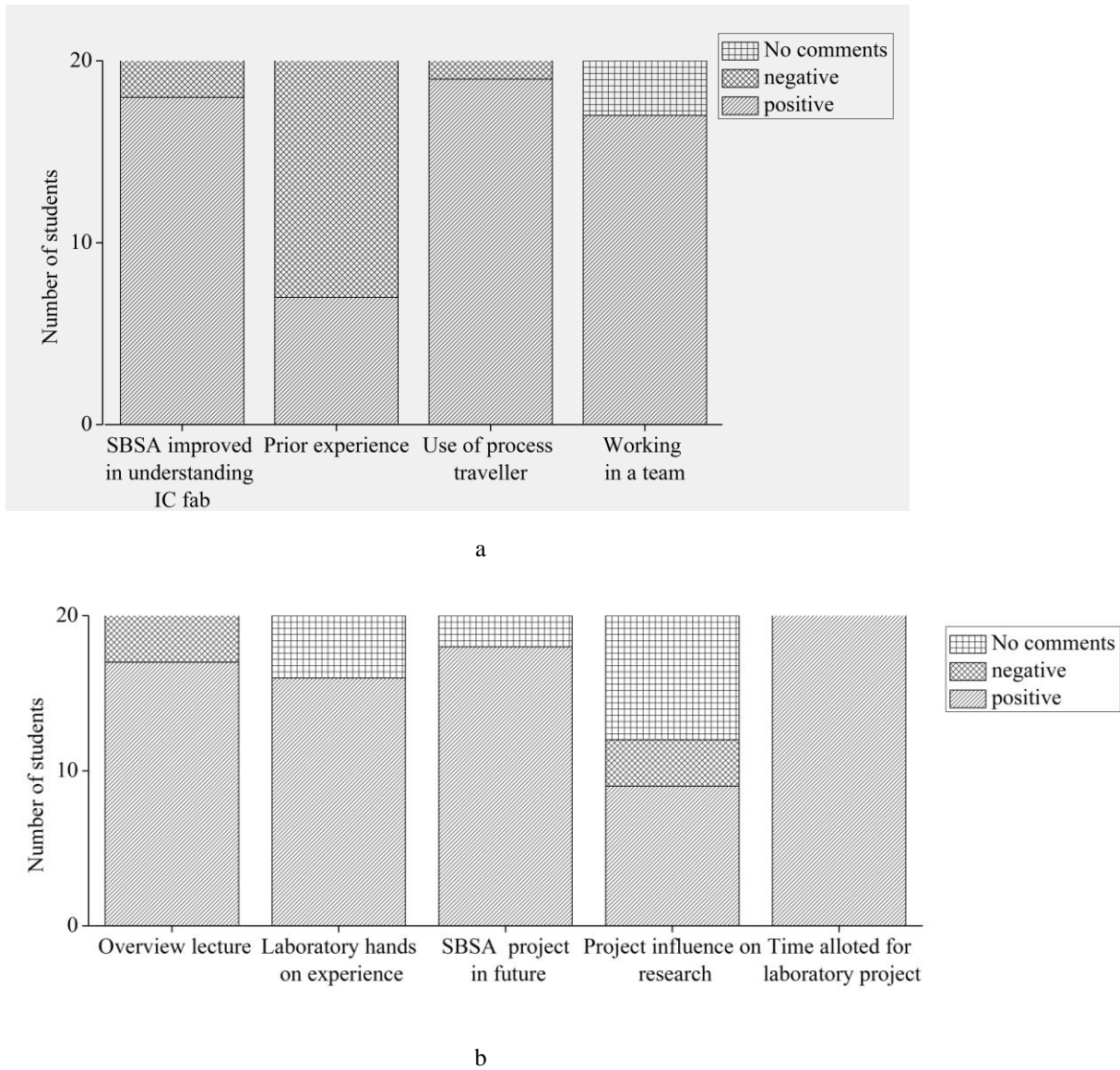


Figure 8. Survey opinions on SBSA project provided by students.

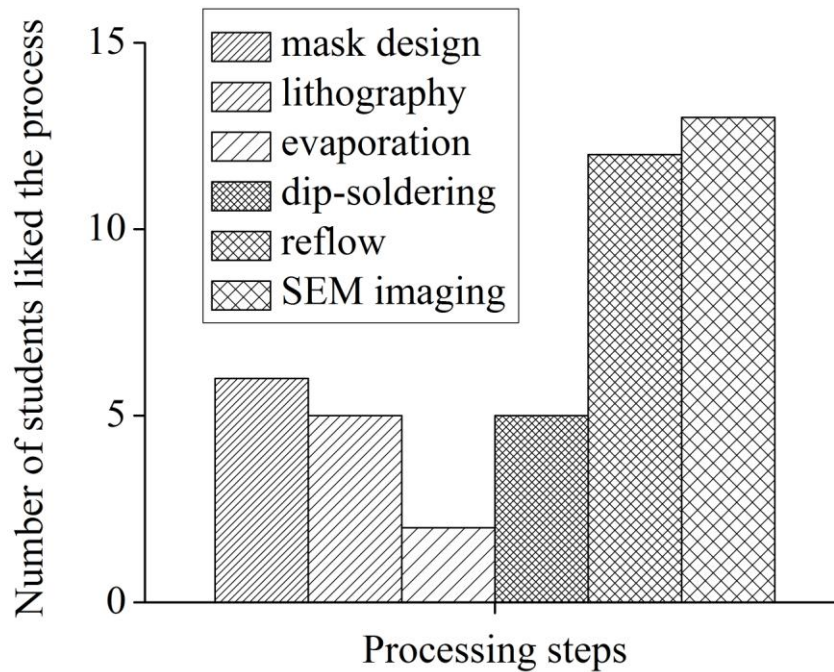


Figure 9. Survey opinions showing the number of students liked each individual processing steps in SBSA project.

Table 5. Time Spent By Instructor On The Laboratory Project.

Steps	Time (hours)
Formation of student groups	1
Brainstorming session	2
Designing masks	3
Wet etching	0.25
Copper plating	2
Resist stripping	0.25
Metal etching	0.25
Photolithography	1
Dip soldering	2
Dicing	0.25
Sacrificial etching	0.25
Reflow	2
Evaluation of presentation and work	4

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AUTHOR INFORMATION

Madhav Rao completed his Masters in Microelectronics and Photonics from University of Arkansas in 2007 and Ph.D in Electrical and Computer Engineering department from the University of Alabama in 2012. He joined IIIT-Bangalore as faculty after graduation. His major research contributions are in the area of solder based self assembly technology, 3D antennas, magnetic logic devices and Carbon nanotubes filled silicon vias. He has interest in taking emerging technologies to the classrooms to keep the curriculum updated and interesting to students.

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